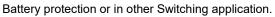


Description

The AP30P10D uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a



General Features

 $V_{DS} = -100V I_{D} = -30 A$

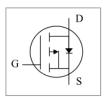
 $R_{DS(ON)}$ < 95m Ω @ V_{GS} =10V

Application

Battery protection

Load switch

Uninterruptible power supply







Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
AP30P10D	TO-252-3L	AP30P10D XXX YYYY	2500

Absolute Maximum Ratings (T_C=25°Cunless otherwise noted)

Symbol	Parameter	Rating	Units
V _D s	Drain-Source Voltage	-100	V
Vgs	Gate-Source Voltage	±20	V
I _D @T _C =25°C	Continuous Drain Current, V _{GS} @ -10V ¹	-30	А
I _D @T _C =100°C	Continuous Drain Current, V _{GS} @ -10V ¹	-15	А
IDM	Pulsed Drain Current ²	-75	A
EAS	Single Pulse Avalanche Energy ³	157.2	mJ
las	Avalanche Current	18.9	А
P _D @T _C =25°C	Total Power Dissipation ⁴	54	W
Тѕтс	Storage Temperature Range	-55 to 150	°C
TJ	Operating Junction Temperature Range	-55 to 150	°C
ReJA	Thermal Resistance Junction-Ambient ¹	62	°C/W
Rejc	Thermal Resistance Junction-Case ¹	2.3	°C/W



Electrical Characteristics (T_J=25°C, unless otherwise noted)

Symbol	Parameter Conditions		Min.	Тур.	Max.	Unit
BVDSS	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =-250uA	-100			V
		V _{GS} =-10V , I _D =-10A		78	95	
Rds(on)	Static Drain-Source On-Resistance ²	V _{GS} =-4.5V , I _D =-8A		86	110	mΩ
VGS(th)	Gate Threshold Voltage	V _{GS} =V _{DS} , I _D =-250uA	-1.2	-1.7	-2.5	V
IDSS	Drain-Source Leakage Current	V _{DS} =-100V , V _{GS} =0V , T _J =25°C			-50	uA
Igss	Gate-Source Leakage Current	V _{GS} =±20V , V _{DS} =0V			±100	nA
gfs	Forward Transconductance	V _{DS} =-10V , I _D =-10A		24		S
Qg	Total Gate Charge			44.5		
Qgs	Gate-Source Charge	V _{DS} =-50V , V _{GS} =-10V , I _D =-20A		9.13		nC
Qgd	Gate-Drain Charge			5.93		
Td(on)	Turn-On Delay Time			12		
Tr	Rise Time	V _{DD} =-50V , V _{GS} =-10V ,		27.4		
T _{d(off)}	Turn-Off Delay Time	—R _G =3.3 , —I _D =-10A		79		ns
Tf	Fall Time	ID IOA		53.6		
Ciss	Input Capacitance			3029		
Coss	Output Capacitance	V _{DS} =-20V , V _{GS} =0V , f=1MHz		129		pF
Crss	Reverse Transfer Capacitance			76		
ls	Continuous Source Current ^{1,5}	V _G =V _D =0V , Force Current			-18	Α
VsD	Diode Forward Voltage ²	V _{GS} =0V , I _S =-1A , T _J =25°C			-1.2	V
trr	Reverse Recovery Time	IF=-8A , di/dt=-100A/μs ,		38.7		nS
Q _{rr}	Reverse Recovery Charge			22.4		nC

Note:

- 1.The data tested by surface mounted on a 1 inch FR-4 board with 2OZ copper.
- 2.The data tested by pulsed , pulse width $\leqq 300 us$, duty cycle $\leqq 2\%$
- 3. The EAS data shows Max. rating . The test condition is V^{DD} =-25V, V^{GS} =-10V, L=0.88mH, IAS=-18.9A
- 4.The power dissipation is limited by 150°C junction temperature
- 5 .The data is theoretically the same as I_D and I_{DM} , in real applications , should be limited by total power dissipation.



Typical Characteristics

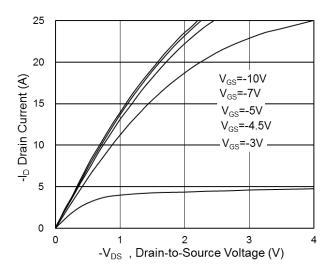


Fig.1 Typical Output Characteristics

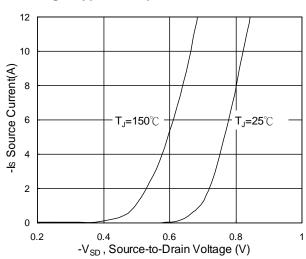


Fig.3 Typical S-D Diode Forward Voltage

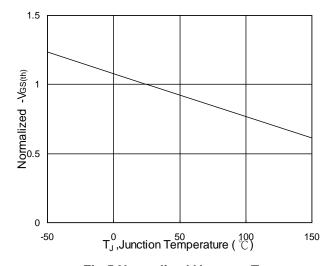


Fig.5 Normalized $V_{\text{GS(th)}}$ vs T_{J}

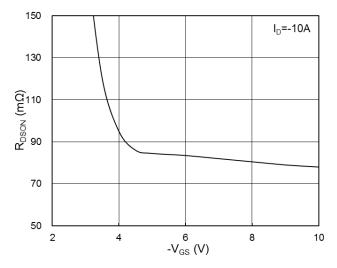


Fig.2 On-Resistance vs G-S Voltage

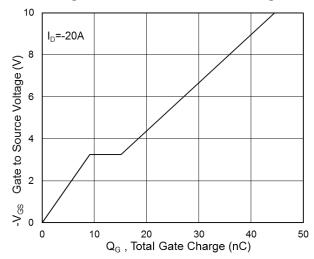


Fig.4 Gate-Charge Characteristics

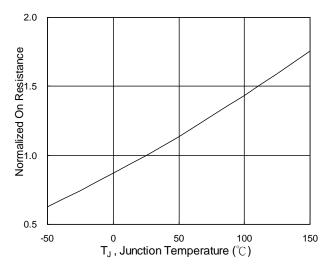
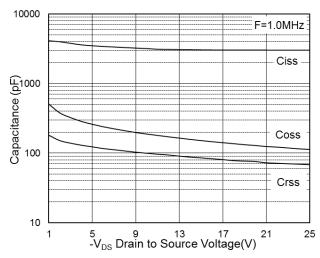


Fig.6 Normalized R_{DSON} vs T_J







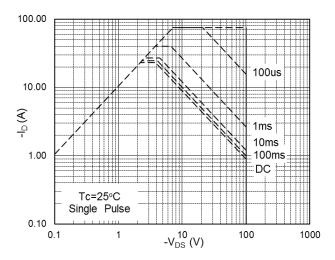


Fig.7 Capacitance

Fig.8 Safe Operating Area

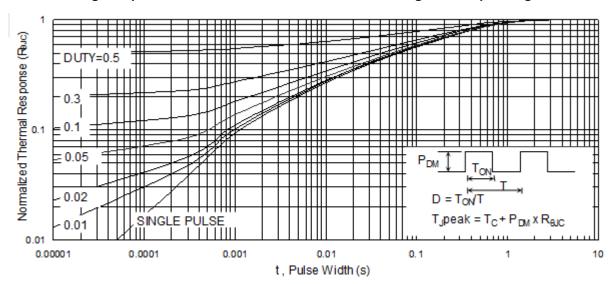


Fig.9 Normalized Maximum Transient Thermal Impedance

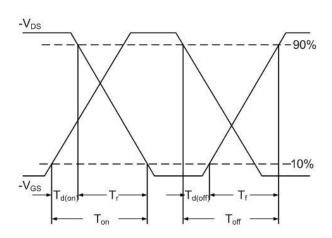


Fig.10 Switching Time Waveform

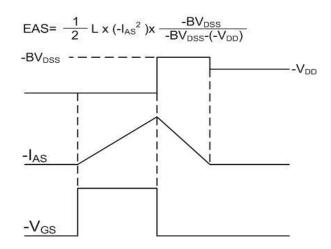
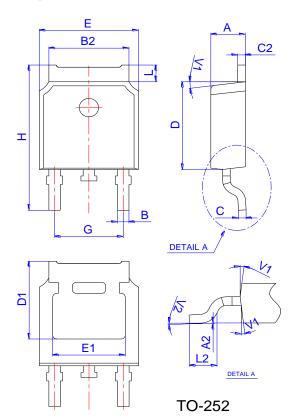


Fig.11 Unclamped Inductive Waveform

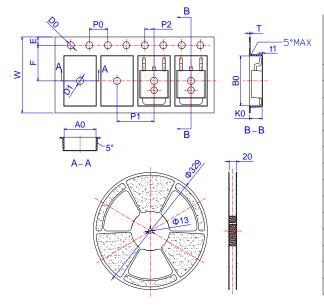


Package Mechanical Data



	Dimensions					
Ref.	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
В	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
С	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
Н	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°

Reel Spectification-TO-252



	Dimensions						
Ref.	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
W	15.90	16.00	16.10	0.626	0.630	0.634	
E	1.65	1.75	1.85	0.065	0.069	0.073	
F	7.40	7.50	7.60	0.291	0.295	0.299	
D0	1.40	1.50	1.60	0.055	0.059	0.063	
D1	1.40	1.50	1.60	0.055	0.059	0.063	
P0	3.90	4.00	4.10	0.154	0.157	0.161	
P1	7.90	8.00	8.10	0.311	0.315	0.319	
P2	1.90	2.00	2.10	0.075	0.079	0.083	
A0	6.85	6.90	7.00	0.270	0.271	0.276	
В0	10.45	10.50	10.60	0.411	0.413	0.417	
K0	2.68	2.78	2.88	0.105	0.109	0.113	
T	0.24		0.27	0.009		0.011	
t1	0.10			0.004			
10P0	39.80	40.00	40.20	1.567	1.575	1.583	



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